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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|-------------------------|-----------------|----------------------|-------------------------|------------------|
| 10/815,370 | 04/01/2004 | Chih Chieh Yeh | MXIC 1571-1 | 8260 |
| 22470 7590 01/12/2005 | | | EXAMINER | |
| HAYNES BE | EFFEL & WOLFELD | PHAN, TRONG Q | | |
| P O BOX 366 | | | | |
| HALF MOON BAY, CA 94019 | | | ART UNIT | PAPER NUMBER |
| | | | 2818 | |
| | | | DATE MAILED: 01/12/2005 | |

Please find below and/or attached an Office communication concerning this application or proceeding.

| | Application No. | Applicant(s) | | | | |
|---|---|--|--|--|--|--|
| Office Action 0 | 10/815,370 | YEH ET AL. | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | TRONG PHAN | 2818 | | | | |
| The MAILING DATE of this communication Period for Reply | appears on the cover sheet with the | he correspondence address | | | | |
| A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFI after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, and if NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by standard patent term adjustment. See 37 CFR 1.704(b). | ON. R 1.136(a). In no event, however, may a reply b. a reply within the statutory minimum of thirty (30' riod will apply and will expire SIX (6) MONTHS latute, cause the application to become ABAND | the timely filed) days will be considered timely. from the mailing date of this communication. ONED (35 U.S.C. § 133). | | | | |
| Status | | | | | | |
| 1)⊠ Responsive to communication(s) filed on <u>21 April 2004</u> . | | | | | | |
| 2a) ☐ This action is FINAL . 2b) ☑ | This action is FINAL. 2b)⊠ This action is non-final. | | | | | |
| ,— | Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. | | | | | |
| Disposition of Claims | | | | | | |
| 4) ☐ Claim(s) 1-65 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-65 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or election requirement. | | | | | | |
| Application Papers | | | | | | |
| 9) ☐ The specification is objected to by the Examiner. | | | | | | |
| 10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner. | | | | | | |
| Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). | | | | | | |
| 11) The oath or declaration is objected to by the | | | | | | |
| Priority under 35 U.S.C. § 119 | | | | | | |
| 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. | | | | | | |
| Attachment(s) | | | | | | |
| 1) Notice of References Cited (PTO-892) | 4) Interview Sumr | nary (PTO-413) ail Date | | | | |
| Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SE Paper No(s)/Mail Date <u>0105</u>. | , <u> </u> | nal Patent Application (PTO-152) | | | | |

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-65 are rejected under 35 U.S.C. 103(a) as being unpatentable over Walukas, 6,229,737, in view of Lin, 6,671,209.

Walukas, 6,229,737, discloses in Fig. 1 a memory device comprising:

a first memory array EEPROM 12 for storing a page of data (see lines 44-45, column 5)
in response to a first interleaving algorithm (se lines 1-3, column 5);
second flash memory array 14 for storing a data bite (see lines 39-42, column 6) in
response to a second interleaving algorithm (see lines 3-6, column 5);
processor CPU 24;
SRAM 22.

What is not shown in Walukas, 6,229,737, is the charge storage non-volatile memory cells as recited in claims 1-65.

Lin, 6,671,209, discloses in Fig. 1 a memory cell which can be used for EEPROM and Flash memory devices (see lines 18-43, column 1) comprising: substrate 10; charge trapping layer 16 of silicon nitride; first tunneling oxide layer 14;

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second dielectric layer 18;

gate electrode 20;

source channel region 22;

drain channel region 24;

erasing by band-to-band hot electron/holes/electric field injection (see lines 44-51, column 1 and lines 31-32, column 2).

It would have been obvious under 35 USC 103(a) to one of ordinary skill in the art at the time of the invention was made to utilize the memory cell in Fig. 1 of Lin, 6,671,209, for the EEPROM array 12 and the Flash memory array 14 in Fig. 1 of Walukas et al., 6,229,737, for the purpose of preventing drain leakage current and reducing power consumption (see lines 11-17, column 2).

Conclusion

3. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Leak et al., 5,937,424, Hsu et al., 6,490,196, Shiau et al., 5,699,298, and Wong , 6,826,084.

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to TRONG PHAN whose telephone number is (571) 272-1794. The examiner can normally be reached on M-F (8:30-5:00).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571)272-1787. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

TRONG PHAN
PRIMARY EXAMINER

Phaworony